

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,303,809 B2
APPLICATION NO. : 09/954515
DATED : December 4, 2007
INVENTOR(S) : Hyung-Chul Choi

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 5,

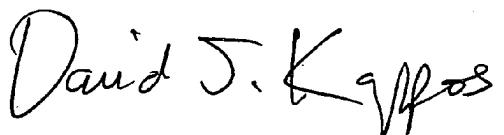
Line 30, Below "100 nm." insert -- Examples of combinations of insulating layers, conductive layers and top layers which have been found to give good results in the present process are given in Table 1 below (in which "ITO" stands for indium tin oxide). --.

Column 8,

Line 34, In Claim 9, delete "cyclopentadinene)" and insert -- cyclopentadiene) --, therefor.

Signed and Sealed this

Twenty-second Day of December, 2009



David J. Kappos
Director of the United States Patent and Trademark Office